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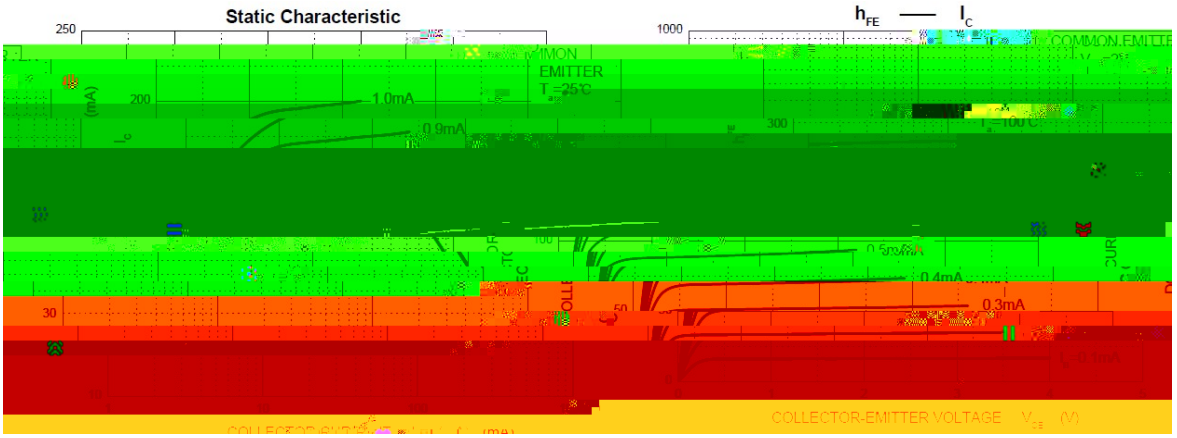
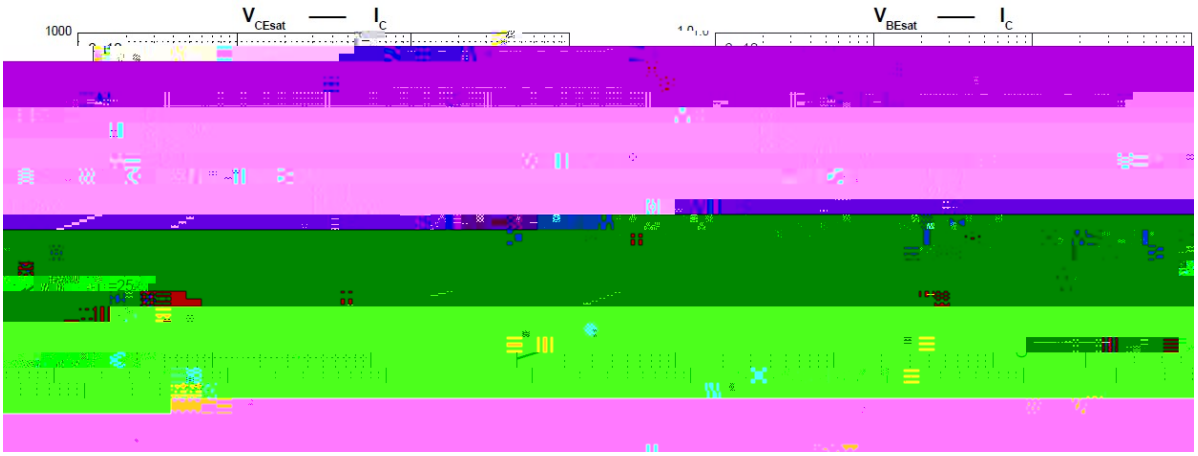
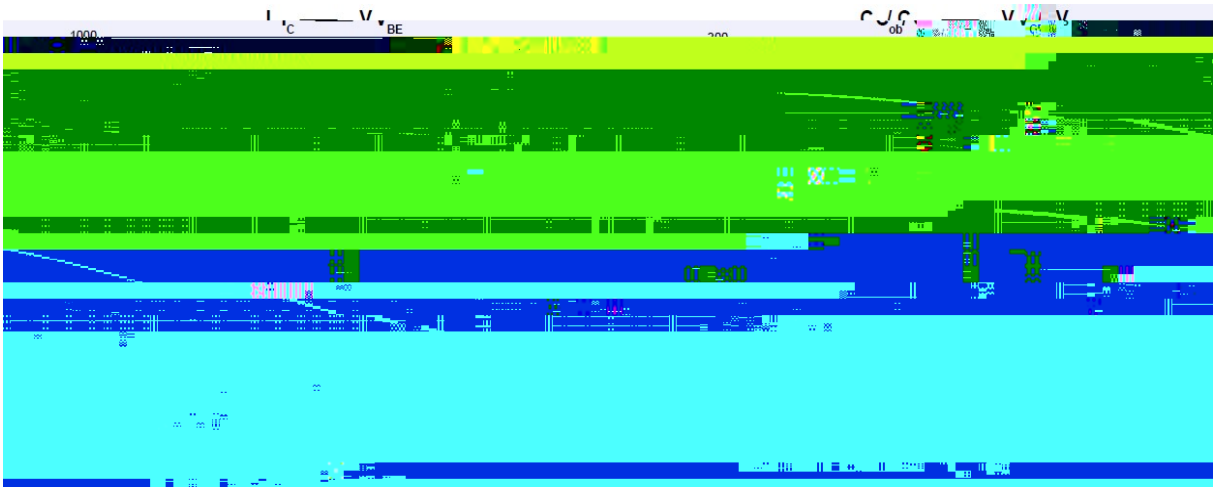
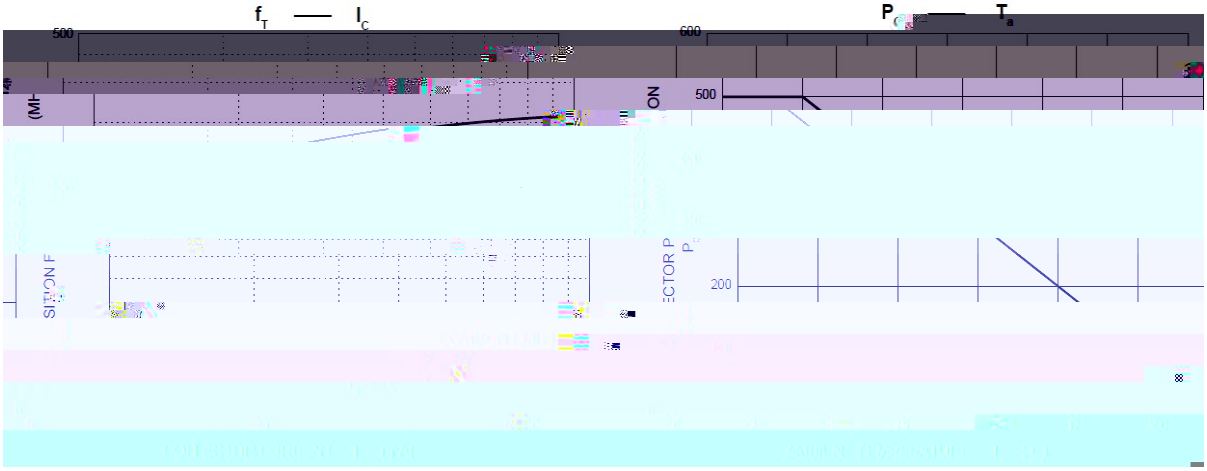

Static Characteristic
250
200
30
1.0mA
0.9mA
0.4mA
0.3mA
COMMON EMITTER
T =25℃
COLLECTOR-EMITTER VOLTAGE
h_{FE} —— I_C
1000
300
50
COMMON EMITTER
T =100℃


V_{CEsat} —— I_C
1000
V_{BEsat} —— I_C


I_C —— V_{BE}
1000
C_{ob} —— V_{CB}


f_T —— I_C
500
(MH
SILICON
P_C —— T_a
600
500
200
COLLECTOR P

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